## **RELIABILITY REPORT**

FOR

## MAX2391EGI

## PLASTIC ENCAPSULATED DEVICES

February 3, 2004

## **MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

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#### Conclusion

The MAX2391 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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## I. Device Description

#### A. General

The MAX2391 fully integrated direct-conversion receiver IC is designed specifically for W-CDMA applications. With the MAX2395, the MAX2391 forms a complete single-mode W-CDMA radio chipset.

The MAX2391 provides a complete antenna-to-baseband solution for the 3GPP W-CDMA FDD receiver (2110MHz to 2170MHz, 3.84Mcps), eliminating the use of an off-chip IF SAW filter, as well as external RX LO generation and synthesis.

The MAX2391 receiver ICs have over 90dB of dynamic gain control, and a receive sensitivity of -112dBm referred to LNA input. The receiver consists of an ultra-low current low-noise amplifier (LNA) with on-chip output matching and a two-step gain control. The zero-IF demodulator has a differential circuit topology for minimum LO leakage to the receiver's input. The channel selectivity is done completely in the baseband section of the receiver with an on-chip lowpass filter. The AGC section has over 50dB of gain control range. LO quadrature generation is done onchip through a divide-by-2 prescaler. The DC offset cancellation in the I/Q baseband channels is done fully on-chip using a DC servo loop. To quickly correct for large DC offset transients in minimal time, very fast settling time is obtained by optimization of the DC-offset cancellation circuit's time constant.

The MAX2391 includes a 3-wire serial bus for PLL programming and for configuring the different receiver modes. It also includes a SHDN pin for full device shutdown. The MAX2391 is fabricated using an advanced high-frequency SiGe BiCMOS process. The IC operates from a single +2.7V to +3.3V supply and is housed in a small 28-pin leadless QFN-EP package (5mm  $\times$  5mm).

Pating

#### B. Absolute Maximum Ratings

Itam

<u>item</u>	Raung
VCC to GND	-0.3V to +3.6V
All Other Pins to GND	-0.3V to (VCC + 0.3V)
LNA_IN	+15dBm
Digital Input Current	±10mA
Digital Output Open-Collector Current	1mA
Operating Temperature Range	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +160°C
Lead Temperature (soldering, 10s)	+300°C
28-Pin QFN	1.667W
Derates above +70°C	
28-Pin QFN	20.8mW/°C

#### II. Manufacturing Information

A. Description/Function: W-CDMA Zero-IF Receivers

B. Process: MB20 Bi-CMOS Process

C. Number of Device Transistors: 8883

D. Fabrication Location: Oregon, USA

E. Assembly Location: Korea

F. Date of Initial Production: January, 2003

## III. Packaging Information

A. Package Type: 28-Pin QFN

B. Lead Frame: Copper

C. Lead Finish: Solder Plate

D. Die Attach: Silver-Filled Epoxy

E. Bondwire: Gold (1.0 mil dia.)

F. Mold Material: Epoxy with silica filler

G. Assembly Diagram: # 05-9000-1020

H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity

per JEDEC standard JESD22-A112: Level 1

#### IV. Die Information

A. Dimensions: 120 x 98 mils

B. Passivation: Si<sub>3</sub>N<sub>4</sub> (Silicon nitride)

C. Interconnect: Au

D. Backside Metallization: None

E. Minimum Metal Width: 1.2 microns (as drawn) Metal 1, 2 & 3 5.6 microns (as drawn) Metal 4

F. Minimum Metal Spacing: 1.6 microns (as drawn) Metal 1, 2 & 3, 4.2 microns (as drawn) Metal 4

G. Bondpad Dimensions: 3.4 mil. Octagonal

H. Isolation Dielectric: SiO<sub>2</sub>

I. Die Separation Method: Wafer Saw

## V. Quality Assurance Information

A. Quality Assurance Contacts: Jim Pedicord (Manager, Reliability Operations)

Bryan Preeshl (Executive Director of QA)

Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

#### A. Accelerated Life Test

The results of the 150°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \text{ x } 9823 \text{ x } 99 \text{ x } 2}$$
 (Chi square value for MTTF upper limit) 
$$\lambda = 4.90 \text{ x } 10^{-9}$$
 Temperature Acceleration factor assuming an activation energy of 0.8eV 
$$\lambda = 4.90 \text{ x } 10^{-9}$$
 
$$\lambda = 4.90 \text{ F.I.T.}$$
 (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on rejects from lots exceeding this level. The attached Burn-In Schematic #06-7084 shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (RR-B2A).

### B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

#### C. E.S.D. and Latch-Up Testing

The WC17-1 die type has been found to have all pins able to withstand a transient pulse of <200V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit).

Latch-Up testing has shown that this device withstands a current of ±250mA.

# **Table 1**Reliability Evaluation Test Results

## MAX2391EGI

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Tes	t (Note 1)			
	Ta = 150°C Biased Time = 192 hrs.	DC Parameters & functionality	99	0
Moisture Testi	ng (Note 2)			
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality	77	0
Mechanical Str	ress (Note 2)			
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality	77	0

Note 1: Life Test Data may represent plastic DIP qualification packages.

Note 2: Generic package/process data.

#### Attachment #1

TABLE II. Pin combination to be tested. 1/2/

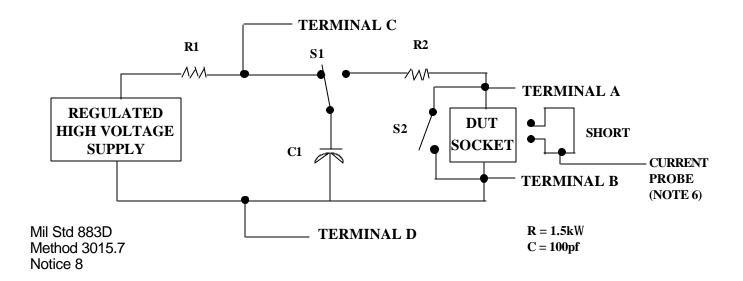
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V <sub>PS1</sub> 3/	All V <sub>PS1</sub> pins
2.	All input and output pins	All other input-output pins

- 1/ Table II is restated in narrative form in 3.4 below.
- 2/ No connects are not to be tested.
- 3/ Repeat pin combination I for each named Power supply and for ground

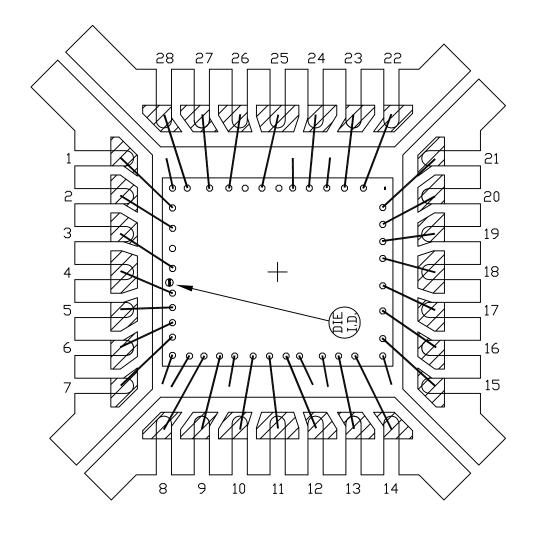
(e.g., where  $V_{PS1}$  is  $V_{DD}$ ,  $V_{CC}$ ,  $V_{SS}$ ,  $V_{BB}$ , GND,  $+V_{S}$ ,  $-V_{S}$ ,  $V_{REF}$ , etc).

## 3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., \( \forall \_{S1} \), or \( \forall \_{S2} \) or \( \forall \_{S3} \) or \( \forall \_{C1} \), or \( \forall \_{C2} \)) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



# EXPOSED PAD PKG.



BONDABLE AREA

PKG. BODY SIZE: 5x5 mm

DOWNBOND DETAILS: DOWNBOND LENGTHS CONTROL DOWNBOND	ARE CRITICAL. LOCATIONS AS SHOWN.
	0.00 (DIE EDGE)  15 MILS MIN  25 MILS MAX

PKG. CODE: G2855-2		SIGNATURES	DATE	CONFIDENTIAL & PROPRIETARY	
CAV./PAD SIZE:	PKG.			BOND DIAGRAM #:	REV:
130×130	DESIGN			05-9000-1020	Α

